

SMC PLASTIC SILICON RECTIFIERS

FEATURES

- •Plastic package has Underwriters Laboratory
- Flammability Classification 94V-O Utilizing
- •Metal silicon junction ,majority carrier conduction

•Built-in strain relief

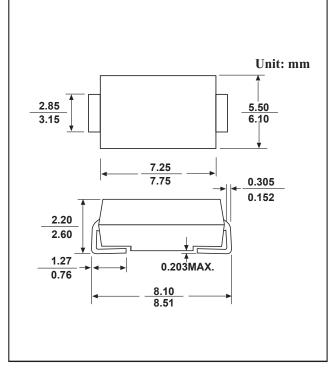
- •For surface mounted applications
- •Low power loss ,high efficiency,High surge capability
- •High current capability ,Low forward voltage drop
- •For use in low voltage ,high frequency inverters, free wheeling and polarity protection applications
 - •High temperature soldering guaranteed:260 °C/10 seconds at terminals
 - •Component in accordance to RoHS 2015/863 and WEEE 2012/19/EU

MECHANICAL DATA

- •Case: SMC molded plastic body
- •Terminals:Lead solderable per MIL-STD-750,method 2026
- Polarity:Color band denotes cathode end

MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)



Parameter	Symbols	SS52	SS54	SS56	SS58	SS510	SS512	SS515	SS520	Units
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V _{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current	I _{F(AV)}	5.0								А
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I _{fsm}	175 150							A	
Max Instantaneous Forward Voltage at 5 A	V _F	0.55		0.70		0.85				V
Maximum DC Reverse Current $T_a = 25^{\circ}C$ at Rated DC Reverse Voltage $T_a = 100^{\circ}C$	۱ _R	1.0 50								mA
Typical Junction Capacitance ⁽¹⁾	Cj	60	00	400						pF
Typical Thermal Resistance ⁽²⁾	R _{0JA}	35								°C/W
Operating Junction Temperature Range	Tj	-55 ~ +150								°C
Storage Temperature Range	T _{stg}	-55 ~ +150								°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C $\,$

(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



RATINGS AND CHARACTERISTIC CURVES

